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SEMICONDUCTOR

CD4030C Quad EXCLUSIVE-OR Gate

General Description

The CD4030C EXCLUSIVE-OR gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. All inputs are protected against static discharge with diodes to $\rm V_{DD}$ and $\rm V_{SS}.$

Features

■ Wide supply voltage range: 3.0V to 15V

- Low power: 100 nW (typ.)
- Medium speed operation:
- t_{PHL} = t_{PLH} = 40 ns (typ.) at C_{L} = 15 pF, 10V supply

October 1987

Revised April 2002

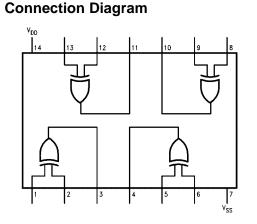
■ High noise immunity 0.45 V_{CC} (typ.)

Applications

- Automotive
- Data terminals
- Instrumentation
- Medical electronics
- Industrial controls
- Remote metering
- Computers

Ordering Code:

Order Number	Package Number	Package Description			
CD4030CSJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide			
CD4030CN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide			
Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.					



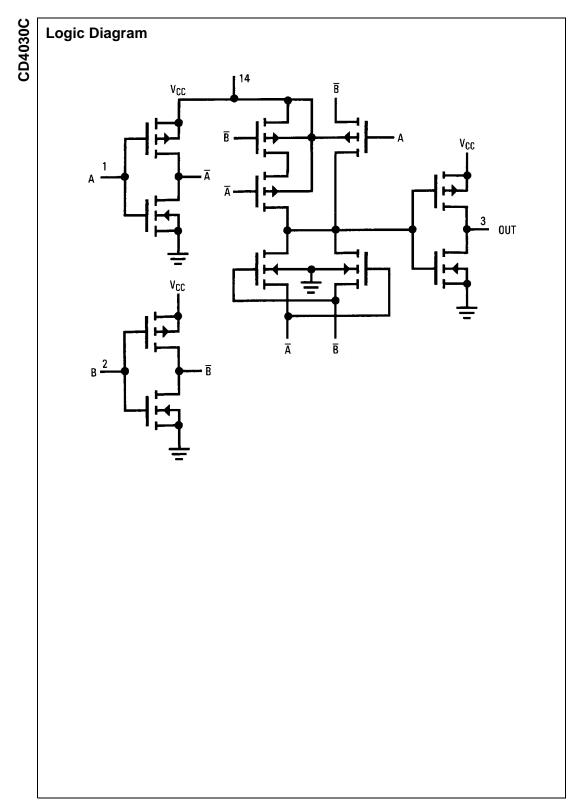
Truth Table

Α	В	J
0	0	0
1	0	1
0	1	1
1	1	0

1 = HIGH Level 0 = LOW Level

DS005961

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Absolute Maximum Ratings(Note 1)

Voltage at Any Pin (Note 2) Operating Temperature Range Storage Temperature Range	V _{SS} –0.3V to V _{SS} +15.5V –55°C to +125°C –65°C to +150°C
Power Dissipation (P _D)	
Dual-In-Line	700 mW
Small Outline	500 mW
Operating V _{DD} Range	$\rm V_{SS}$ +3.0V to $\rm V_{SS}$ +15V
Lead Temperature	
(Soldering, 10 seconds)	260°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions for actual device operation.

Note 2: This device should not be connected to circuits with power on because high transient voltages may cause permanent damage.

DC Electrical Characteristics

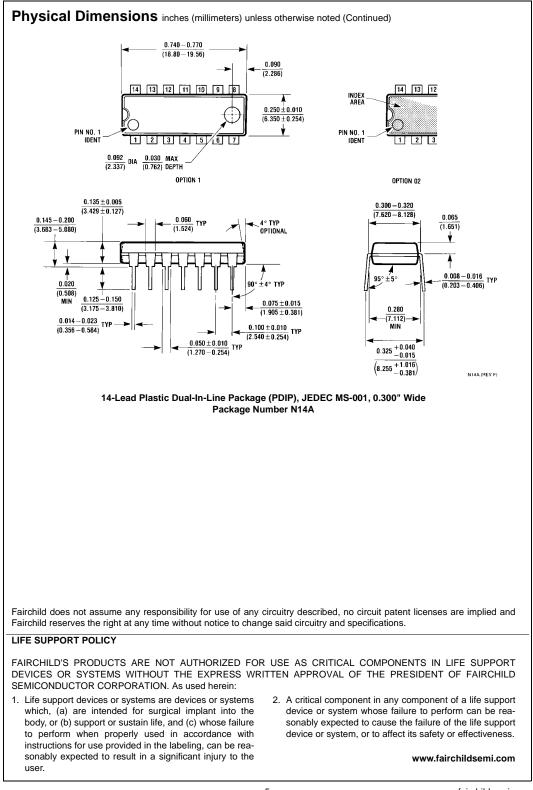
Symbol	Parameter	Conditions	–55°C		+25°℃			+125°C			Units		
Symbol			Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	onits	
IL.	Quiescent Device	$V_{DD} = 5.0V$			0.5		0.005	0.5			30	μA	
	Current	$V_{DD} = 10V$			1.0		0.01	1.0			60	μА	
PD	Quiescent Device	$V_{DD} = 5.0V$			2.5		0.025	2.5			150	μW	
	Dissipation Package	$V_{DD} = 10V$			10		0.1	10			600		
V _{OL}	Output Voltage	$V_{DD} = 5.0V$			0.05		0	0.05			0.05	V	
	LOW Level	$V_{DD} = 10V$			0.05		0	0.05			0.05	v	
V _{OH}	Output Voltage	$V_{DD} = 5.0V$	4.95			4.95	5.0		4.95			V	
	HIGH Level	$V_{DD} = 10V$	9.95			9.95	10		9.95			v	
V _{NL}	Noise Immunity	$V_{DD} = 5.0V$	1.5			1.5	2.25		1.4			V	
	(All Inputs)	$V_{DD} = 10V$	3.0			3.0	4.5		2.9			v	
V _{NH}	Noise Immunity	$V_{DD} = 5.0V$	1.4			1.5	2.25		1.5			V	
	(All Inputs)	$V_{DD} = 10V$	2.9			3.0	4.5		3.0			v	
I _D N	Output Drive Current	$V_{DD} = 5.0V$	0.75			0.6	1.2		0.45			mA	
	N-Channel (Note 3)	$V_{DD} = 10V$	1.5			1.2	2.4		0.9			11A	
I _D P	Output Drive Current	$V_{DD} = 5.0V$	-0.45			-0.3	-0.6		-0.21			mA	
	P-Channel (Note 3)	V _{DD} = 10 V	-0.95			-0.65	-1.3		-0.45				
I _I	Input Current	$V_I = 0V \text{ or } V_I = V_{DD}$				1	10					pА	

Note 3: I_DN and I_DP are tested one output at a time.

AC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions		Limits			
		Conditions	Min	Тур	Max	Units	
t _{PHL}	Propagation Delay Time	V _{DD} = 5.0V		100	300	ns	
		$V_{DD} = 10V$		40	150		
t _{PLH}	Propagation Delay Time	V _{DD} = 5.0V	_{DD} = 5.0V 100	300			
		$V_{DD} = 10V$		40	150	ns	
t _{THL}	Transition Time	V _{DD} = 5.0V		70	300		
	HIGH-to-LOW Level	$V_{DD} = 10V$		25	150	ns	
t _{TLH}	Transition Time	V _{DD} = 5.0V		80	300		
	LOW-to-HIGH Level	$V_{DD} = 10V$		30	150	ns	
CI	Input Capacitance	$V_I = 0V \text{ or } V_I = V_{DD}$		5.0		pF	

Note 4: AC Parameters are guaranteed by DC correlated testing.



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